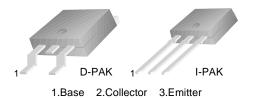


KSH200

D-PAK for Surface Mount Applications

- High DC Current Gain
- Built-in a Damper Diode at E-C
- Lead Formed for Surface Mount Applications (No Suffix)
- Straight Lead (I-PAK, " I " Suffix)



NPN Epitaxial Silicon Transistor

Absolute Maximum Ratings $T_C=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Value	Units
V _{CBO}	Collector-Base Voltage	40	V
V _{CEO}	Collector-Emitter Voltage	25	V
V _{EBO}	Emitter-Base Voltage	8	V
I _B	Base Current	1	Α
I _C	Collector Current (DC)	5	А
I _{CP}	Collector Current (Pulse)	10	Α
P _C	Collector Dissipation (T _C = 25°C)	12.5	W
	Collector Dissipation (T _a = 25°C)	1.4	W
T _J	Junction Temperature	150	°C
T _{STG}	Storage Temperature	- 55 ~ 150	°C

Electrical Characteristics $T_C=25$ °C unless otherwise noted

Symbol	Parameter	Test Condition	Min.	Max.	Units
V _{CBO} (sus)	* Collector Emitter Sustaining Voltage	I _C =100mA, I _B =0	25		V
I _{CEO}	Collector Cut-off Current	V_{CB} =40V, I_{E} =0		100	nA
I _{CBO}	Collector Cut-off Current	V _{EBO} =8V, I _C =0		100	nA
I _{EBO}	Emitter Cut-off Current	V _{CE} =1V, I _C =500mA	70		
h _{FE}	* DC Current Gain	V _{CE} =1V, I _C =2A V _{CE} =2V, I _C =5A	45 10	180	
V _{CE} (sat)	* Collector-Emitter Saturation Voltage	I _C =500mA, I _B =50mA I _C =2A, I _B =200mA I _C =5A, I _B =1A		0.3 0.75 1.8	V V V
V _{BE} (sat)	* Base-Emitter Saturation Voltage	I _C =5A, I _B =2A		2.5	V
V _{BE} (on)	* Base-Emitter On Voltage	V _{CE} =1V, I _C =2A		1.6	V
f _T	Current Gain Bandwidth Product	V _{CE} =10V, I _C =100mA	65		MHz
C _{ob}	Output Capacitance	V _{CB} =10V, I _E =0, f=0.1MHz		80	pF

^{*} Pulse Test: PW≤300µs, Duty Cycle≤2%

Typical Characteristics

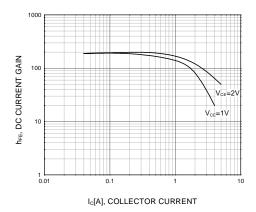


Figure 1. DC current Gain

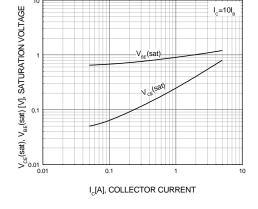


Figure 2. Base-Emitter Saturation Voltage Collector-Emitter Saturation Voltage

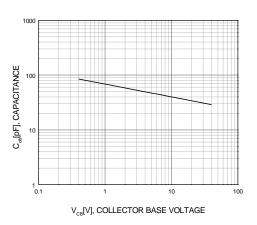


Figure 3. Collector Output Capacitance

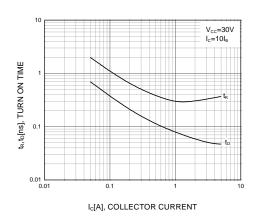


Figure 4. Turn On Time

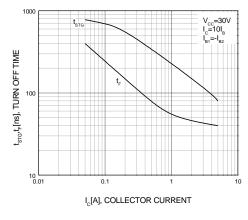
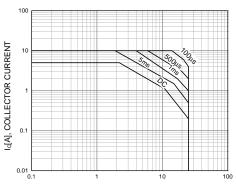


Figure 5. Turn Off Time



 $V_{\text{CE}}[V]$, COLLECTOR-EMITTER VOLTAGE

Figure 6. Safe Operating Area

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Typical Characteristics (Continued)

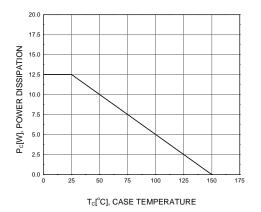
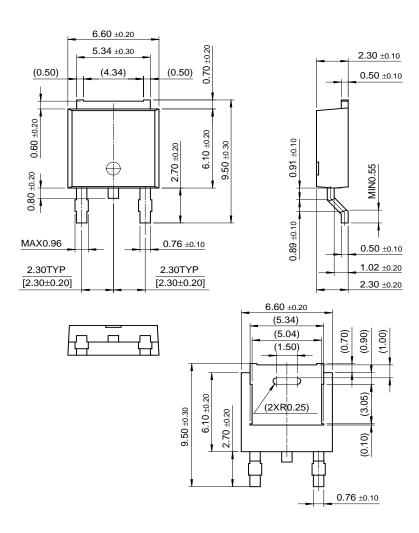


Figure 7. Power Derating

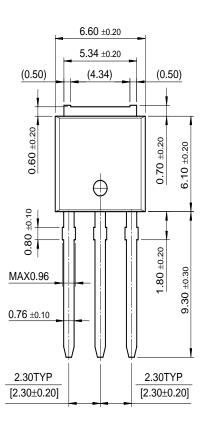
Package Dimensions

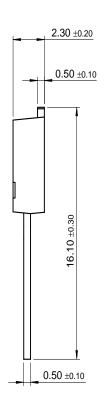
D-PAK



Package Dimensions (Continued)

I-PAK







Dimensions in Millimeters

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CoolFET™	FASTr™	MicroFET™	PowerTrench [®]	SuperSOT™-6
$CROSSVOLT^{TM}$	FRFET™	MicroPak™	QFET™	SuperSOT™-8
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Programmable Active Droop™		OPTOPLANAR™	SMART START™	

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